

MBRF1030CT THRU MBRF10100CT

Isolation 10.0 AMPS. Schottky Barrier Rectifiers



Voltage Range 30 to 100 Volts Current

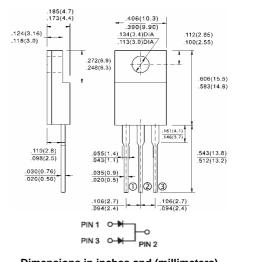
Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Leads solderable per MIL-STD-750, Method
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. lbs. max
- Weight: 0.08 ounce, 2.24 grams

10.0 Amperes ITO-220AB



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 1030 CT	MBRF 1035 CT	MBRF 1040 CT	MBRF 1045 CT	MBRF 1050 CT	MBRF 1060 CT		Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	30	35	40	45	50	60	100	V
Maximum RMS Voltage	V _{RMS}	21	24	28	31	35	42	70	V
Maximum DC Blocking Voltage	V _{DC}	30	35	40	45	50	60	100	V
Maximum Average Forward Rectified Current at T _c =133°C	I _(AV)	10							Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=133°C	I _{FRM}	10.0						Α	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150						Α	
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	0.5						Α	
Maximum Instantaneous Forward Voltage at (Note 2) $I_{F}=5A,Tc=25^{\circ}C$ $I_{F}=5A,Tc=125^{\circ}C$ $I_{F}=10A,Tc=25^{\circ}C$ $I_{F}=10A,Tc=125^{\circ}C$	V_{F}	0.70 0.57			-	80 65	0.85 0.75 0.95 0.85	V	
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25°C @ Tc=125°C	I _R	0.1 15					0.15 150	mA mA	
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000						V/uS	
RMS Isolation Voltage (t=1.0 second, R.H. ≤30%, TA=25°C) (Note 4) (Note 5) (Note 6)	V_{ISO}	4500 3500 1500						V	
Typical Thermal Resistance Per Leg (Note 3) ${\sf R}\theta{\sf JC}$	$R\theta JC$	3.5						℃\M	
Operating Junction Temperature Range T _J	T_J	-65 to +150						${\mathbb C}$	
Storage Temperature Range TSTG	Tstg	-65 to +150							${\mathbb C}$

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case Per Leg.
- 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.
- 5. Clip mounting (on case), where leads do overlap heatsink. 6. Screw mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")



